NSN 5961-01-088-1347

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-088-1347

Inclosure Material:

Metal

Overall Length:

Between 0.170 inches and 0.210 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.209 inches and 0.230 inches

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

T0-18

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

mounting

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Gold plated leads and hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

200.00 milliamperes source cutoff current

Power Rating Per Characteristic:

360.0 milliwatts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0